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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of: Jyunichi NAKAMURA et al. Confirmation No.: 5720
Serial No.: 10/649,745 Art Unit: 2826
Filed: August 28, 2003 Examiner: A. WILLIAMS
For: **MULTILAYERED SUBSTRATE
FOR SEMICONDUCTOR
DEVICE** Atty Docket No: 060914-117-US

AMENDMENT

U.S. Patent and Trademark Office
Randolph Building
104 Dulany Street
Alexandria, Virginia 22314

Sir:

In response to the outstanding Office Action dated December 9, 2004, please amend the above-referenced patent application in light of the following amendments and remarks.

Amendments to the specification begin on page 2 of this amendment;

Amendment to the claims begin at page 3; and

Remarks begin at page 5 of this amendment.